OEM SOLUTIONS AESTHETIC AND MEDICAL APPLICATIONS

Astrum LT

Long-pulsed green laser 532nm up to 5J Long-pulsed yellow laser 583nm up to 5J Q-Switch Nd:Yag up to 1.7J Long-pulsed Nd:Yag up to 70J Picosecond Nd:Yag up to 0.5J at 200ps 755nm, 808nm, or 1064nm hair removal kit, high power, custom spot size Tm CW & pulsed module up to 120W

ISO 13485:2016

LASER TECHNOLOGY BY ASTRUM LT

Astrum LT, UAB (Vilnius, Lithuania) is an international developer, and supplier of high power laser systems and components. Astrum LT supplies all well-known laser types - Nd:Yag, diode, KTP, Erbium, Holmium, Thulium, Q-switched and picosecond lasers - for such applications as cosmetology, aesthetic medicine and industrial processing/cutting/engraving of metals and other materials.





The enterprise was founded in 2017 and completely focuses on semiconductor laser technology. The semiconductor technology offers higher efficiency, improved reliability and provides various technical capabilities. The company provides laser and optical components, modules, and accessories that provide for full cycle manufacturing of laser systems.

	Flash-lamp pumping	Semiconductor		
Technology	Conventional	Advanced		
Laser source life time	Flash lamp, up to a year Diode, five years m			
Optical power and energy	High	High		
Maintenance	Third-party, high costs	User, low costs		
Pulse repetition rate	1-15Hz	1-100Hz		
Emission efficiency	<5%	~50%		
Power consumption	High	Low		
Cost of ownership	High	Low		





Astrum LT today:

- an ISO 13485:2016 certifed production
- a supplier of innovations and production research in laser technologies for medical and industrial application.
- a holder of patents for unique proprietary technologies.
- a team of qualifed professionals, including medical advisers, and engineers of doctorate and highest academic degree.
- quality, reliability, efficiency of laser systems.
- single source for design and development, manufacturing of components, assembly.

Q-Switch Nd:YAG/KTP kit

Complete OEM solution for a Q-switch Nd:Yag laser system: laser module, driver, control and cooling system

	 Semiconductor laser system GUI Mindows UNIQUE Q-switch + long pulse in a single module 1.7J 						
	Wavelength, nm	10	532				
	Operation mode	Long pulse	Q-switched	Q-switched			
	Pulse energy, J	110	1.7	0.7			
	Max fluence, J/cm ²	3,600	54	23			
	Pulse length	0.3 – 60ms	5 - 10ns	5 - 10ns			
	Max pulse repetition rate, Hz	50	50	50			
	Cooling system	Air-liquid, integrated					
	Beam aperture, mm		9mm				
7ns 7ns 7ns 7ns 7ns 7ns	7ns No hot spots	FL	AT-TOP BEAM PRO	DFILE			





- A pulse (300mks 60ms) in a long-pulsed mode can be controllably divided into 1, 2 or 3 sub-pulses, each at a chosen energy level. Such customization turns a simple laser beam into a controlled, precise and finely adjusted tool to effectively treat targeted lesions but avoid damaging neighboring tissue.
- The Q-switched mode features a double-pulse routine, each pulse 7ns long with preset energy levels and 140mks between them. Use different energy patterns when applying the double pulse mode to secure a cascade effect which is a combination of mechanical and thermal actions, so that only chromophores are targeted, and no neighboring tissue is damaged.

	ESIGN	OR RECEIVE A COMPLETELY ASSEMBLED	
	Diode-pumped 1064/532nm laser module Laser control board and system		
	Closed-circuit water cooling system	MELSTECH	
and a state	Laser diode driver	 0 0 0	

Astrum LT

Semiconductor lasers systems and components

532-808-1064nm laser kit

Complete OEM solution for a 532-808-1064nm laser system: laser module, driver, control and cooling system

.



The three-wave module provides for application of various modes within a single procedure by switching between the wavelengths in seconds, which makes it universal for a wide range of medical applications. The diode-pumping technology eliminates any flash lamps in the laser systems, and therefore is not subject to cumbersome and expensive aftersales service.

EATURES

- Semiconductor laser system
- GUI 🖉
- UNIQUE tri-wave optical module and a single optical
- Fiber handpiece
- 5-100W
- Easilly transforms into 532nm single wave
- Small blueprint
- Customized wavelengths upon request

Wavelength, nm	1064	808	532			
Mode	Q-switched modulated long pulse	Q-switched modulated long pulse				
Max pulse energy, mJ	300	900	150			
Pulse length	10ms - 2s					
Max energy density, J/cm ²	270	800	140			
Max pulse repetition rate, Hz	50	50	50			
Max average power, W	30	90	10			
Max pulse power, W	30,000	90	15,000			
Cooling system	liq	juid, integrate	d			
Spot size		1.2 – 10mm				





755nm, 808nm, 1060nm Hair removal laser kit, -6°C skin cooling

Complete OEM solution for a hair removal laser system: laser module with sapphire skin cooling, laser diode driver, control and cooling system.



FEATURES

High power VCSEL chips inside

Astrum LT

Semiconductor lasers

- •
- GUI Mindows or 📫 200W Peltier cooling •
- Standard or custom spot size
- Treatment protocol support
- 808, 755 or 1060nm
- Any wavelength, same chassi



Astrum LT

Semiconductor lasers systems and components

Wavelength - 755nm

- Power 1800W
- Design edge emitting laser bars
- Pulse length 5 30ms
- Spot size 10x10mm
- Max fluence 30J/cm²
- Max repetition rate 5Hz

Fluence vs Pulse length



Fluence vs Max Repetition Rate (Hz)



Wavelength - 755nm

- Power 1600W
- Design edge emitting laser bars
- Pulse length 5 70ms
- Spot size 10x10mm
- Max fluence 80J/cm²
- Max repetition rate 10Hz

Fluence vs Pulse length





Fluence vs Max Repetition Rate

Wavelength - 1060nm

- Power 1600W
- Design edge emitting laser bars
- Pulse length 5 70ms
- Spot size 10x10mm
- Max fluence 80J/cm²
- Max repetition rate 10Hz

Fluence vs Pulse length







Wavelength - 808nm

- Power 1000W
- Design edge emitting laser bars
- Pulse length 10 60ms
- Spot size 10x10mm
- Max fluence 40J/cm²
- Max repetition rate 10Hz



Fluence vs Max Repetition Rate (Hz)



The stated power value is the total emitting power of the package, whereas the performance graphs take account of optical losses.

Astrum LT Semiconductor lasers

Wavelength - 808nm

- Power 2400W .
- Design edge emitting laser bars
- Pulse length 5 70ms
- Spot size 10x25mm
- Max fluence 48J/cm²
- Max repetition rate 10Hz

Fluence vs Pulse length



Fluence vs Pulse length

48 64 80 96 128 160

Pulse length, ms

60

50

Fluence, J/cm² 70 00 1/cm²

10

0

16 32 Fluence vs Max Repetition Rate (Hz)



Fluence vs Max Repetition Rate (Hz)



Wavelength - 808nm

- Power 1200W
- Design VCSEL
- Pulse length 15 160ms
- Spot size 10x10mm
- Max fluence 50J/cm² .

Wavelength - 808nm

Power - 1800W

Design - edge emitting laser bars

Pulse length – 5 - 70ms

Spot size – 10x10mm

Max fluence - 90J/cm²

Max repetition rate - 10Hz

Max repetition rate - 10Hz .



Fluence vs Max Repetition Rate (Hz)



Wavelength - 808nm

- Power 4000W .
- Design edge emitting laser bars
- Pulse length 3 30ms .
- Spot size 10x25mm
- Max fluence 40J/cm² .
- Max repetition rate 9Hz .





The stated power value is the total emitting power of the package, whereas the performance graphs take account of optical losses.

Tm:YAG laser solution, 2020nm Urology application: surgery & lithotripsy in a single design

Complete OEM solution for urology application: optical module with temperature stabilization, laser diode driver, control and cooling system.



In urinary tissues, water is the main chromophore absorbed by thulium laser radiation. In surgical applications, thulium laser radiation effectively cuts tissue and provides the required level of coagulation. Absorption depth in the prostate is only 0.4 mm, creating a high energy density sufficient for vaporization: dissipating heat causes simultaneous coagulation of small blood vessels to a depth of about 2 mm; this enables precise, char-free and virtually bloodless incision in prostatic tissue. The main mechanism of laser lithotripsy is heating and dramatically expanding the water contained in the stone pores. This leads to microexplosions, destroying the material of the stone.

FEATURES

- High power
 - GUI 🚚 🐉 or 🏢
- CW and Pulsed mode in a single solution
- CW up to 200W
- Pulsed 0.1-2ms up to 1500W
- Fiber output 600micron



TM:YAG LASER APPLICATION IN UROLOGY:

Surgical	Lithotripsy
Benign prostatic hyperplasia (BPH)	Stone fragmentation
Adenoma (ThuLEP)	Stone dusting
Urothelial tumors	Kidney stones
Strictures	Bladder stones
Tunnel and bladder neck incision	All type of stones including calcium oxalate monohydrate (COM)



Nd:YAG laser module for gynecology

Complete OEM solution for gynecological application: optical module with temperature stabilization, laser diode driver, control and cooling system.



FEATURES

.

.

- Solid and reliable design
- GUI 🚮 or 👘
- QCW up to 30W
- Pulse burst length 0.5 100ms
- Pulse energy up to 750mJ
- 600micron optical fiber out

KTP (Nd:YAG SHG)

Nd:YAG

- Treatment guide support
- Treatment tools options

The neodymium laser radiation with a wavelength of 1064 nm deeply penetrates (up to 5-10 mm) into soft tissues. Moderate absorption of radiation with this wavelength in water and hemoglobin ensures uniform and deep heating of the vaginal walls. Use of the Nd:YAG laser radiation in gynecology is non-ablative and non-coagulative, and respectively non-invasive. Heating the collagen to a temperature of 45-60°C leads to shrinkage of collagen, and absorption in hemoglobin stimulates the growth of a small vascular network. All of these effects lead to a thickening of the vaginal walls and the restoration of blood circulation.



Stress urinary incontinence

- Vaginal relaxation syndrome
- Genitourinary syndrome of menopause

Vaginal prolapse I-II degree

Vulvovaginal atrophy

Recovery after gynecology



Tm:YAG

lo:YAG

CO₂

TREATMENT TOOLS

- cone mirror tool for 360° treatment
- 90° mirror tool for specific area treatment
- straight tool for outer urethra tissue treatment.

Picosend Nd:YAG 1064/532nm laser module

Complete OEM picosecond laser solution: optical module with temperature stabilization, laser diode driver, control and cooling system



FEATURES

- Solid and reliable design
- 🔹 GUI 🚛 ಶ or 👘
 - True picosecond pulsing
 - High energies

•

Pigmentation, tattoo ink, and rejuvenation

Ultra-short pulse laser pulses enable significant photomechanical stresses to targets. The system delivers very high peak powers so quickly that the target is disrupted. Faster, safer treatments.

Wavelength, nm	1064	532
Pulse length, ps	100-200	100-200
Max pulse repetition rate, Hz	20	20
Max output energy, J	0,5	0,25
Max fluence, J/cm2	16,0	8,0
Beam aperture, mm	12	12

Er:YAG laser solution Dermatology application

Complete OEM solution for dermatology application: optical module with temperature stabilization, laser diode driver, control and cooling system



ER:YAG LASER APPLICATION IN DERMATOLOGY:

Cold pilling
Hot pilling
Dermabrasion
Skin resurfacing
Scars abrasion
Fractional ablation for skin rejuvenation
Neoplasms ablation
Onychomycosis treatment

FEATURES

- Wavelength 2940nm
- GUI 🝠 or 👘
- Pulsed mode 0.1 2ms
- Max pulse energy 2J
- Max pulse repetition rate 100Hz
- 600micron SMA 905 connector

Er:YAG laser wavelength is strongly absorbed in water, that leads to high ablation rate of soft tissues. The main mechanism of soft tissues ablation by erbium laser radiation is heating and dramatically expanding the water contained in the tissues. This leads to microexplosions, destroying the material of the skin without overheating and carbonization of surrounding tissue. The coagulation width at the edges of ablative lesions in the skin without traumatic coagulation lesions. The erbium laser allows the "cold" skin treatment by removing ultra-thin layers of tissue with minimal thermal damage including polishing of epithelium up to the basal membrane.



Long pulsed green laser 532nm

Complete OEM solution for dermatology application: optical module with temperature stabilization, laser diode driver, control and cooling system.





Complete OEM solution for dermatology application: optical module with temperature stabilization, laser diode driver, control and cooling system.

_	FEATURES	
•	Wavelength GUI 🧦 or 🚔	583nm
•	Power Beam profile Fiber output	3.5 kW near Gaussian flat top
•	Mode	Multimode

Operation mode	quasi-continuous
Pulse energy @ 10ms	L8.0
Pulse energy @ 60ms	5J
Pulse length	10-60ms
Max pulse repetition rate, Hz	18Hz
Beam divergence	< 3 mrad
Beam aperture, mm	up to 3mm

LASER DIODE DRIVERS OFF-THE-SHELF and CUSTOM BUILT









CW Laser Diode Driver LDD2400-60A-CW

- Maximum output current CW 60 A
- Maximum output current pulsed 200 A
- Maximum output voltage 48 V (at supply voltage 52 V)
- Supply voltage 44...52 V
- Rise/Fall time < 100 us (at Rload ≤ 15 0hm)
- Current regulation < 1 % of maximum output current
- Output current monitor 50 mV/A
- Output voltage monitor 200 mV/V

CW Laser Diode Driver LDD350-100A-CW

- Maximum output current CW 100 A
- Maximum output current pulsed 100 A
- Maximum output voltage 3.5 V
- Supply voltage 8...15 V
- Rise/Fall time < 100 us (at Rload ≤ 10 m0hm)
- Current regulation < 1 % of maximum output current
- Output current monitor 100 mV/A
- Output voltage monitor 2.5 V/V

CW Laser Diode Driver LDD480-12A-CW

- Maximum output current CW 12 A
- Maximum output current pulsed 12 A
- Maximum output voltage 48 V (at supply voltage 56 V)
- Supply voltage 44...56 V
- Rise/Fall time < 250 us (at Rload ≤ 1 0hm)
- Current regulation < 1 % of maximum output current
- Output current monitor 833 mV/A
- Output voltage monitor 200 mV/V

Pulsed Laser Diode Driver LDD1200-150A-QCW

- Pulse rate * (Fp) 0...1000 Hz
- Pulse duration * (Tp) 0.1...100 ms
- Maximum output pulse current * (Io) ≤ 150 A
- Average output power * (Pa) ≤ 1200 W
- Maximum output voltage * (Vo) 160 V (at supply voltage 200 V)
- Supply voltage 160...225 V
- Rise/Fall time < 20 us (at Rload ≤ 1 0hm)
- Current regulation < 1 % of maximum output current
- Output current monitor 62.5 mV/A
- Output voltage monitor 40 mV/V

CW LDD series

Continous mode of operation

Operating DC supply voltage, V	12	12	12	24	48	48	48	48	48	72
Max output current, A	100	70	70	15	12	15	100	70	50	50
Max output voltage, V	3,3	3	2,7	20	40	40	40	40	40	60
Electric output, W	330	210	190	300	480	600	4000	2800	2000	3000
Reduced error of output current setting, max %	0,5	0,5	0,5	0,5	0,5	0,5	0,5	0,5	0,5	0,5
External control	+	+	+	+	+	+	+	+	+	+

Pulsed LDD series

Pulsed mode of operation

Operating DC supply voltage, V	12	24	48	48	48	48	48	190	210
Max output current, A	80	15	15	100	60	200	150	180	180
Max output voltage, V	3,3	20	20	40	40	40	40	150	190
Max pulse length at max current	1ms	1ms	1ms	60ms	60ms	60ms	60ms	1ms	1ms
Rise/fall, µs	80	80	80	120	120	120	120	20	20
Long pulsed mode/max pulse length, ms	60	60	60	60	60	60	60	60	60
Max output current at max pulse length, A	80	15	15	100	60	200	150	60	55
Duty ratio, %	20	20	20	20	20	15	15	5	5
Max electrical input power, W	60	70	140	900	550	1400	1000	1500	1800
Reduced error of output current setting, max %	0,5	0,5	0,5	0,5	0,5	0,5	0,5	0,5	0,5
External control	+	+	+	+	+	+	+	+	+
Additional bank of capacitors	-	-	-	+	+	+	+	+	+

Astrum LT Semiconductor lasers

systems and components

Long-pulsed Nd:YAG/KTP kit

Complete OEM solution for a long-pulsed Nd:Yag laser system: laser module, driver, control and cooling system

•

.

•



FEATURES

- Semiconductor laser system
- GUI 🐙
- UNIQUE semiconductor long pulse
- 3,600 fluence, 60ms

Wave length, nm	1064
Operation mode	Free running
Max pulse energy	110J
Max energy density	3,600J/cm ²
Pulse length	0.3 – 60ms
Max pulse repetition rate, Hz	50
Cooling system	Air-liquid, integrated
Spot size, mm	2-10mm



Modules, amplifiers and components



Astrum LT

OEM Solutions Aesthetic and Medica Applications

CONTACT Astrum LT, UAB

address: LT-10224, 15, Sauletekio al., Vilnius, Lithuania

tel +370 521-432-42,

e-mail tss@astrum-lasers.com

web astrum-lasers.com